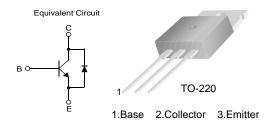


July 2008

FJP5304D NPN Silicon Transistor

High Voltage High Speed Power Switch Application

- Wide Safe Operating Area
- Built-in Free Wheeling diodeSuitable for Electronic Ballast Application
- Suitable for Electronic Ballast Application
- Small Variance in Storage Time



Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	700	V	
V _{CEO}	Collector-Emitter Voltage	400	V	
V _{EBO}	Emitter-Base Voltage	12	V	
I _C	Collector Current (DC)	4	Α	
I _{CP}	* Collector Current (Pulse)	8	Α	
I _B	Base Current (DC)	2	Α	
I _{BP}	* Base Current (Pulse)	4	Α	
P _C	Collector Dissipation (T _C =25°C)	70	W	
T _{STG}	Storage Temperature	- 65 ~ 150	°C	

^{*} Pulse Test Pulse Width = 5ms, Duty Cycle \geq 1.0%

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = 1 \text{mA}, I_{E} = 0$	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{C} = 5mA, I_{B} = 0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA, I _C = 0	12			V
I _{CES}	Collector Cut-off Current	V _{CE} = 700V, V _{EB} = 0			100	mA
I _{CEO}	Collector Cut-off Current	V _{CE} = 400V, IB = 0			250	mA
I _{EBO}	Emitter Cut-off Current	V _{EB} = 12V, I _C = 0			100	mA

h _{FE}	DC Current Gain	$V_{CE} = 5V$, $I_C = 10$ mA $V_{CE} = 5V$, $I_C = 2$ A	10 8		40	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 0.5A, I_B = 0.1A$ $I_C = 1A, I_B = 0.2A$ $I_C = 2.5A, I_B = 0.5A$			0.7 1.0 1.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 0.5A, I_B = 0.1A$ $I_C = 1A, I_B = 0.2A$ $I_C = 2.5A, I_B = 0.5A$			1.1 1.2 1.3	V
V _f	Internal Diode Forward Voltage Drop	I _F = 2A			2.5	V
Inductive L	oad Switching (V _{CC} = 200V)					
t _{stg}	Storage Time	$I_C = 2A$, $I_{B1} = 0.4A$		0.6		μS
tf	Fall Time	$V_{BE}(off) = -5V, L = 200\mu H$		0.1		
Resistive L	oad Switching (V _{CC} = 250V)					•
t _{stg}	Storage Time	$I_C = 2A$, $I_{B1} = I_{B2} = 0.4A$			2.9	μS
tf	Fall Time	T _P = 30μs		0.2		

^{*} Pulse test: PW \leq 300 μ s, Duty cycle \leq 2%

Thermal Characteristics

Symbol	Parameter	Max.	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.78	°C/W
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient	62.5	°C/W

Typical Characteristics

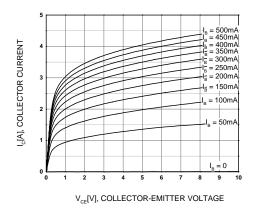


Figure 1. Static Characteristic

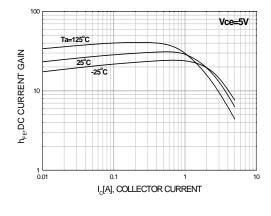


Figure 2. DC Current Gain

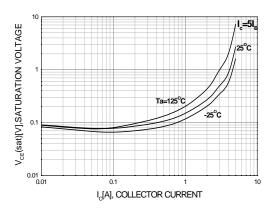


Figure 3. Collector-Emitter Saturation Voltage

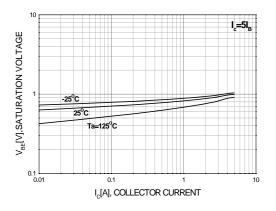


Figure 4. Base-Emitter Saturation Voltage

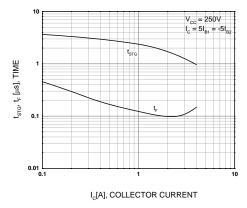


Figure 5. Resitive Load Switching Time

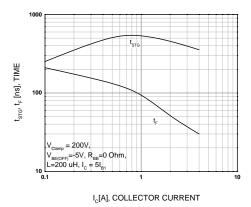


Figure 6. Inductive Load Switching Time

Typical Characteristics (Continued)

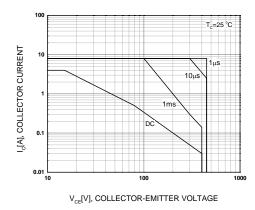


Figure 1. Forward Bias Safe Operating Area

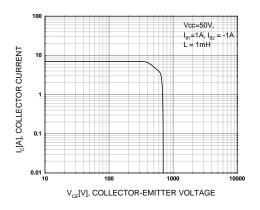


Figure 2. Reverse Bias Safe Operating Area

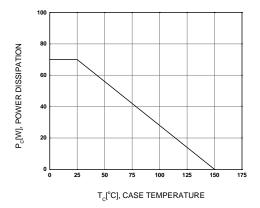


Figure 3. Power Derating







TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ F-PFS™ AttitudeEngine™ FRFET®

Global Power ResourceSM Awinda[®] AX-CAP®*

GreenBridge™ BitSiC™ Green FPS™ Build it Now™ Green FPS™ e-Series™

CorePLUS™ Gmax™ CorePOWER™ $\mathsf{GTO}^{\mathsf{TM}}$ CROSSVOLT™ IntelliMAX™ CTL™ ISOPLANAR™

Current Transfer Logic™ Making Small Speakers Sound Louder

DEUXPEED® and Better™ Dual Cool™ MegaBuck™ EcoSPARK® MIČROCOUPLER™ EfficientMax™ MicroFET™

MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ Fairchild Semiconductor®

MotionGrid® FACT Quiet Series™ MTi[®] FACT[®] MTx® FastvCore™ MVN® FETBench™ mWSaver® FPS™ OptoHiT™ OPTOLOGIC® OPTOPLANAR®

Power Supply WebDesigner™ PowerTrench®

PowerXSTI

Programmable Active Droop™ OFFT

QS™ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™

SignalWise™ SmartMax™ SMART START™

Solutions for Your Success™

SPM® STEALTH™ SuperFET® SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET™ Sync-Lock™

SYSTEM SYSTEM TinyBoost[®] TinyBuck[®] TinyCalc™ TinyLogic[®] TINYOPTO™

TinvPower™ TinyPWM™ TinyWire™ TranSiC™ TriFault Detect™

TRUECURRENT®* սSerDes™

UHC Ultra FRFET™

UniFET™ VCX™ VisualMax™ VoltagePlus™ XSTM. Xsens™ 仙童®

ESBC™

-®

Fairchild®

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR <u>AIRCHILDSEMI.COM.</u> FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application - including life critical medical equipment - where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com,

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Definition of Terms						
Datasheet Identification	Product Status	Definition				
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.				
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.				
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.				
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.				

Rev 177

^{*} Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: FJP5304DTU FJP5304D